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9 5 : .> / / x 4 6 4 ! - } â ’ož Silicon NPN transistor in a SOT-23 Plastic Package.

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2 3 ; mož

Complementary pair with L8550M.

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Power amplifier applications.

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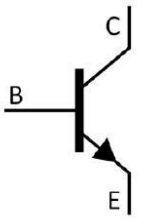

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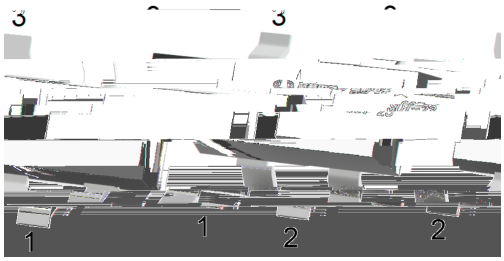

PIN1 y Base PIN 2 y Emitter PIN 3 y Collector

Z Ü B , M V

@ ƒ Parameter	… Z Symbol	ƒ › Rating	% y Unit
Collector to Base Voltage	V		

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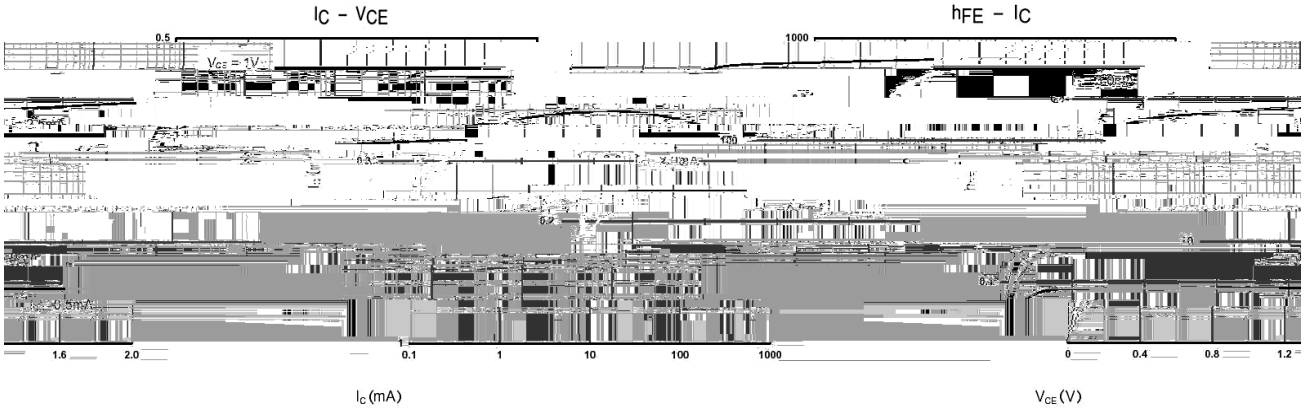

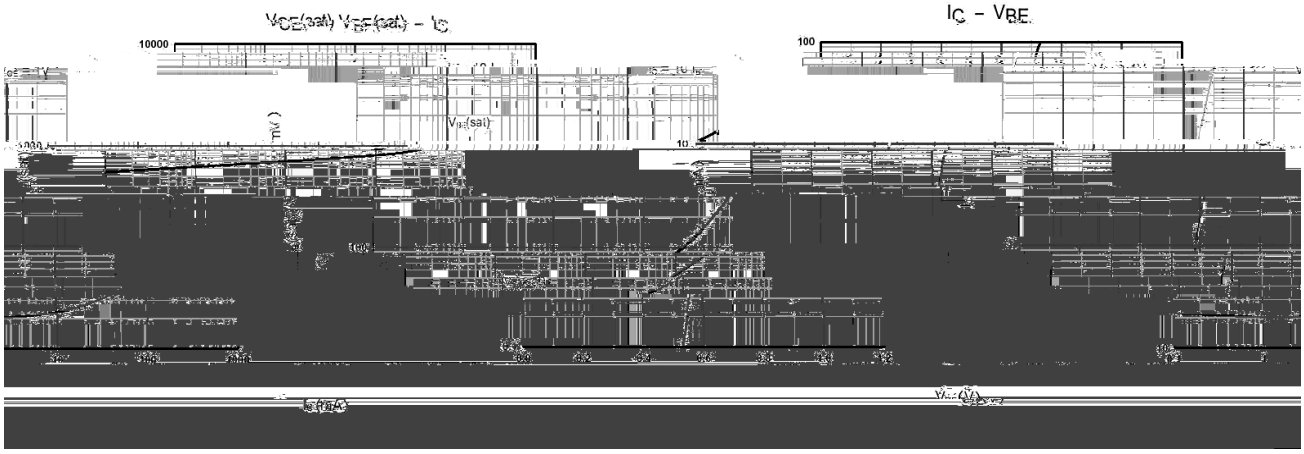

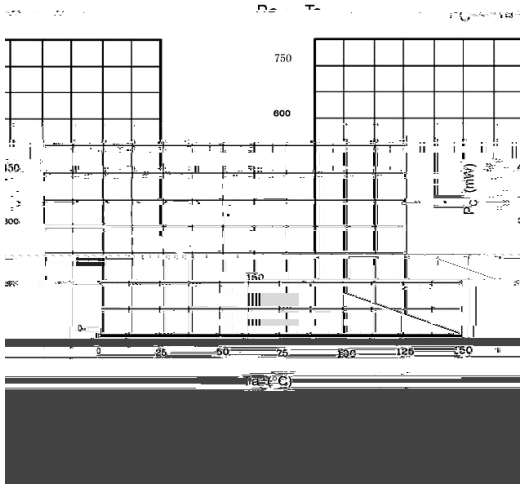

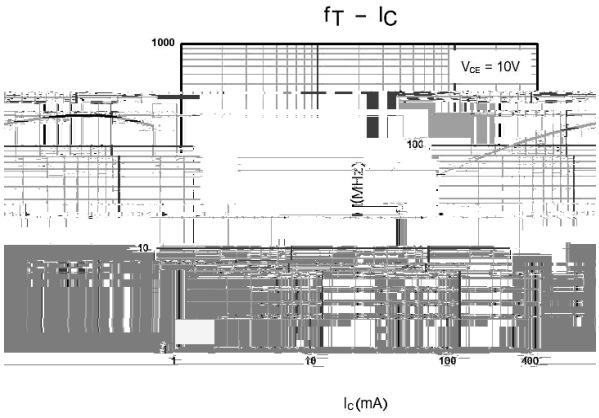

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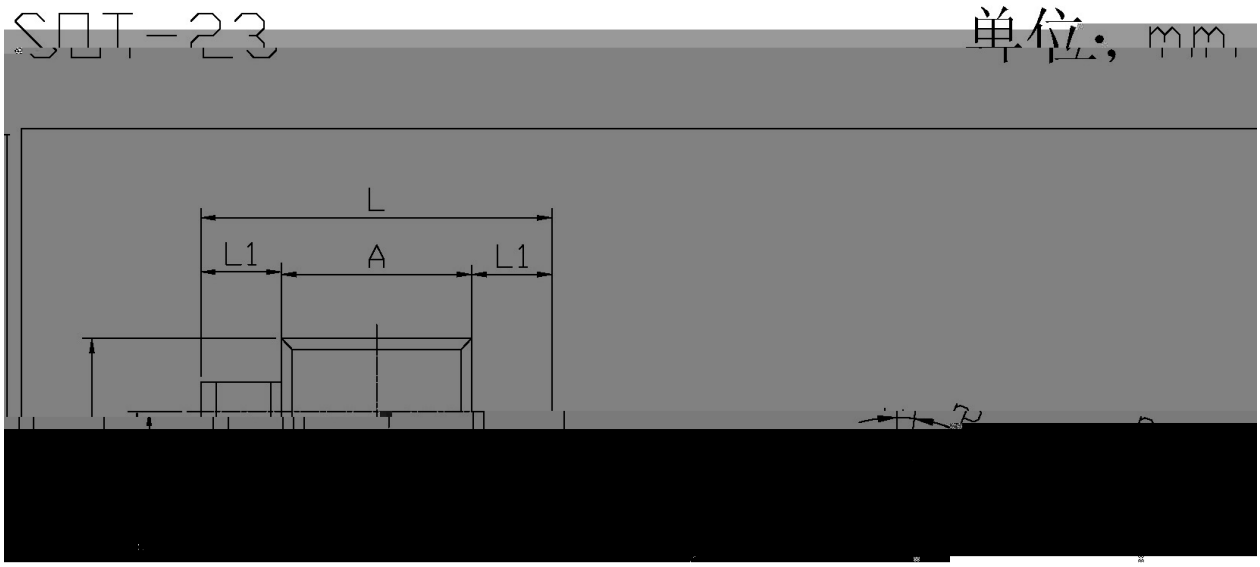
SOT-23 单位：mm



Symbol	Min	Max	Symbol	Min	Max
			L	2.2	2.7
			C		1.30Ma
1.20			L1	0.45	0.65
			C1	0.90	
0.20			A	1.15	1.50
			c	0.05	
0.10			B	2.70	3.10
			K	0	
7°			E1	0.85	1.05
			P		
			b	0.35	0.55

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š WD t ... • Ž ¢ x / :K S V K X G Z [X K 6 X U L O R K L U X / 8 8 K L R U] 9 U R J K X O T M 6

ª ¢ y

1o• Ä ½ “ † 150 ½180 - k ž • 60 ½90sec;

2o• Q › “ † 245 r 5 - k ž • 4 Ò 5 r 0.5sec;

3o•D N ò i Ò 0 , † 2 ½10 - /sec.

Note:

1.Preheating:150~180 - , Time:60~90sec.

2.Peak Temp.:245 r 5 - , Duration:5 r 0.5sec.

3. Cooling Speed: 2~10 - /sec.

ÂD /Cã p10 »]

“ † y 260 r 5 - ž • y 10 r 1 sec.

Temp.:260 r 5 - Time:10 r 1 sec

G P á

2 & x / REEL